NCV4276

Low-Drop Voltage Regulator

This industry standard linear regulator has the capability to drive loads up to 400 mA at 5.0, 3.3, 2.5 and 1.8 V. Package options include DPAK and D^{2}PAK. This device is pin−for−pin compatible with the Infineon part number TLE4276.

Features

- 5.0, 3.3, 2.5 and 1.8 V; ±4%; Output Voltage at 400 mA
- 500 mV (max) Dropout Voltage
- Inhibit Input
- Very Low Current Consumption
- Fault Protection
    - +45 V Peak Transient Voltage
    - −42 V Reverse Voltage
    - Short Circuit
    - Thermal Overload
- NCV Prefix for Automotive and Other Applications Requiring Site and Control Changes
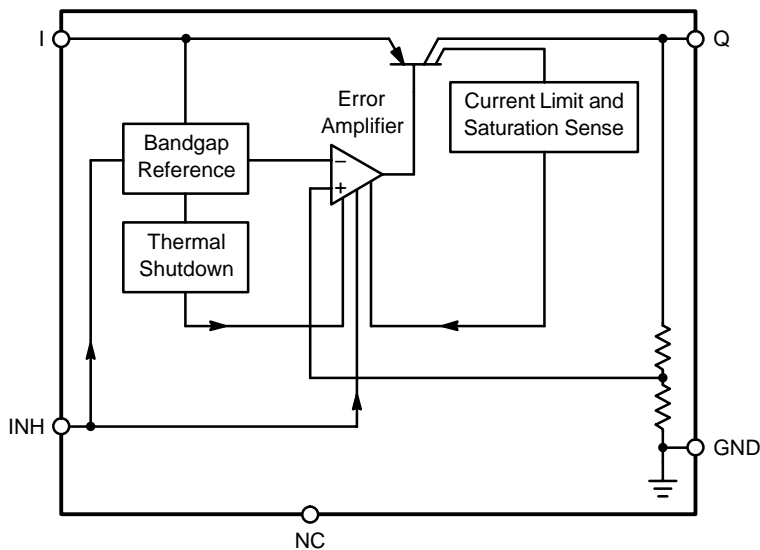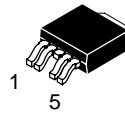
MARKING DIAGRAMS
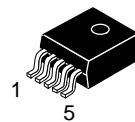
DPAK
5−PIN
DT SUFFIX
CASE 175AA

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4276
ALYWW
     x
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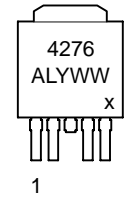
D^{2}PAK
5−PIN
DS SUFFIX
CASE 936A

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NCV4276
AWLYYWW
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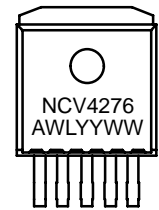
Pin   1. I
          2. INH
Tab, 3. GND*
          4. NC
          5. Q

* Tab is connected to Pin 3 on all packages.

A   = Assembly Location
WL, L   = Wafer Lot
YY, Y   = Year
WW   = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information in the ordering information section on page 9 of this data sheet.

Figure 1. Block Diagram

NCV4276

PIN FUNCTION DESCRIPTION

Pin No.	Symbol	Description
1	I	Input; Battery Supply Input Voltage.
2	INH	Inhibit; Set low−to inhibit.
3	GND	Ground; Pin 3 internally connected to heatsink.
4	NC	Not Connected for fixed voltage versions.
5	Q	Output; ±4.0%, 400 mA output. Use 22 μF, ESR < 2.0 Ω at 10 kHz to ground. See Figure 3.

MAXIMUM RATINGS†

Rating		Min	Max	Unit
Input [I (DC)]		−42	45	V
Input [I (Peak Transient Voltage)]		–	–	V
Inhibit INH		−42	45	V
Output (Q)		−1.0	40	V
Ground (GND)		–	100	mA
Operating Range (I)		Q + 0.5	40	V
ESD Susceptibility (Human Body Model)		4.0	–	kV
(Machine Model)		200	–	V
Junction Temperature		−40	150	°C
Storage Temperature		−50	150	°C
Lead Temperature Soldering	Reflow (SMD styles only) Note 1	–	240 Peak (Note 3)	°C
	Wave Solder (through hole styles only) Note 2	–	260 Peak	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Parameter	Test Conditions (Typical Value)		Unit

DPAK 5−PIN PACKAGE

	Min Pad Board (Note 4)	1″ Pad Board (Note 5)	
Junction−to−Tab (psi−JLx, ψ_{JLx})	4.2	4.7	C/W
Junction−to−Ambient (R$_{\theta JA}$, θ_{JA})	100.9	46.8	C/W

D²PAK 5−PIN PACKAGE

	0.4 sq. in. Spreader Board (Note 6)	1.2 sq. in. Spreader Board (Note 7)	
Junction−to−Tab (psi−JLx, ψ_{JLx})	3.8	4.0	C/W
Junction−to−Ambient (R$_{\theta JA}$, θ_{JA})	74.8	41.6	C/W

1. 10 seconds max.
2. 60 seconds max above 183°C.
3. −5°C/+0°C allowable conditions.
4. 1 oz. copper, 0.26 inch² (168 mm²) copper area, 0.62″ thick FR4.
5. 1 oz. copper, 1.14 inch² (736 mm²) copper area, 0.62″ thick FR4.
6. 1 oz. copper, 0.373 inch² (241 mm²) copper area, 0.62″ thick FR4.
7. 1 oz. copper, 1.222 inch² (788 mm²) copper area, 0.62″ thick FR4.
†During the voltage range which exceeds the maximum tested voltage of I, operation is assured, but not specified. Wider limits may apply. Thermal dissipation must be observed closely.

NCV4276

ELECTRICAL CHARACTERISTICS (V_I = 13.5 V; −40°C < T_J < 150°C; unless otherwise noted)

| Characteristic	Test Conditions	Min	Typ	Max	Unit
Output					
Output Voltage, 5.0 V Version	5.0 mA < I_Q < 400 mA, 6.0 V < V_I < 28 V	4.8	5.0	5.2	V
Output Voltage, 5.0 V Version	5.0 mA < I_Q < 200 mA, 6.0 V < V_I < 40 V	4.8	5.0	5.2	V
Output Voltage, 3.3 V Version	5.0 mA < I_Q < 400 mA, 6.0 V < V_I < 28 V	3.168	3.300	3.432	V
Output Voltage, 3.3 V Version	5.0 mA < I_Q < 200 mA, 6.0 V < V_I < 40 V	3.168	3.300	3.432	V
Output Voltage, 2.5 V Version	5.0 mA < I_Q < 400 mA, 6.0 V < V_I < 28 V	2.4	2.5	2.6	V
Output Voltage, 2.5 V Version	5.0 mA < I_Q < 200 mA, 6.0 V < V_I < 40 V	2.4	2.5	2.6	V
Output Voltage, 1.8 V Version	5.0 mA < I_Q < 400 mA, 6.0 V < V_I < 28 V	1.728	1.800	1.872	V
Output Voltage, 1.8 V Version	5.0 mA < I_Q < 200 mA, 6.0 V < V_I < 40 V	1.728	1.800	1.872	V
Output Current Limitation	–	400	630	1100	mA
Output Current Limitation (Sleep Mode) $I_q = I_I − I_Q$	INH = 0 V, T_J < 100°C	–	0.5	10	µA
Quiescent Current, $I_q = I_I − I_Q$	I_Q = 1.0 mA	–	130	220	µA
Quiescent Current, $I_q = I_I − I_Q$	I_Q = 250 mA	–	10	15	mA
Quiescent Current, $I_q = I_I − I_Q$	I_Q = 400 mA	–	20	35	mA
Dropout Voltage, 5.0 V Version 3.3 V Version 2.5 V Version 1.8 V Version	I_Q = 250 mA, $V_{dr} = V_I − V_Q$	– – – –	250 – – –	500 1.2 2.0 2.7	mV V V V
Load Regulation	I_Q = 5.0 mA to 400 mA	−35	10	35	mV
Line Regulation	∆V = 12 V to 32 V, I_Q = 5.0 mA	−25	2.5	25	mV
Power Supply Ripple Rejection	f_r = 100 Hz, V_r = 0.5 V_{pp}	–	60	–	dB
Temperature Output Voltage Drift	–	–	0.5	–	mV/K
Inhibit					
Inhibit On Voltage	V_Q ≥ 4.8 V	–	2.8	3.5	V
Inhibit Off Voltage	V_Q ≤ 0.1 V	0.5	1.7	–	V
Input Current	V_{INH} = 5.0 V	5.0	10	20	µA
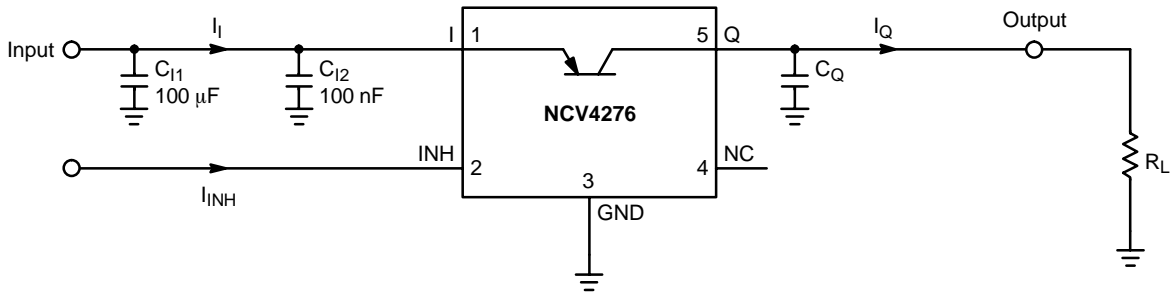
Figure 2. Measuring Circuit

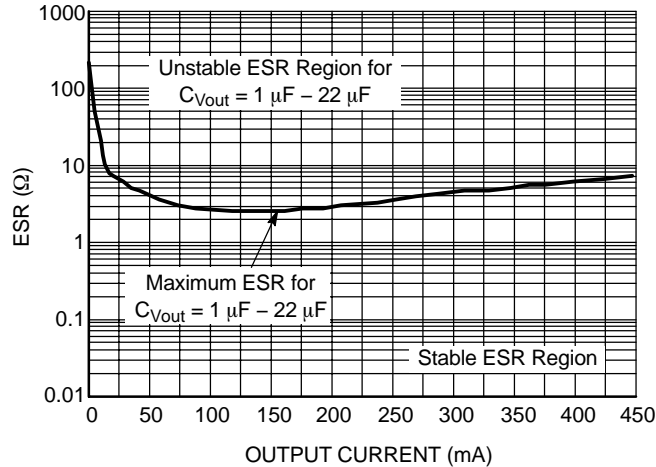**TYPICAL PERFORMANCE CHARACTERISTICS**

**Figure 3. Output Stability with Output
Capacitor ESR**

Circuit Description

The error amplifier compares a temperature–stable reference voltage to a voltage that is proportional to the output voltage (Q) (generated from a resistor divider) and drives the base of a series transistor via a buffer. Saturation control as a function of the load current prevents any oversaturation of the output power device preventing excessive substrate current (quiescent current).

**Calculating Power Dissipation
in a Single Output Linear Regulator**

The maximum power dissipation for a single output regulator (Figure 4) is:

$$P_{D(max)} = [V_{I(max)} - V_{Q(min)}]I_{Q(max)} \qquad (1)$$
$$+ V_{I(max)}I_q$$

where

$V_{I(max)}$	is the maximum input voltage,
$V_{Q(min)}$	is the minimum output voltage,
$I_{Q(max)}$	is the maximum output current for the application,
I_q	is the quiescent current the regulator consumes at $I_{Q(max)}$.

Once the value of $P_{D(max)}$ is known, the maximum permissible value of $R_{\theta JA}$ can be calculated:

$$R_{\theta JA} = \frac{150°C - T_A}{P_D} \qquad (2)$$

The value of $R_{\theta JA}$ can then be compared with those in the package section of the data sheet. Those packages with $R_{\theta JA}$ less than the calculated value in Equation 2 will keep the die temperature below 150°C.

In some cases, none of the packages will be sufficient to dissipate the heat generated by the IC, and an external heatsink will be required.
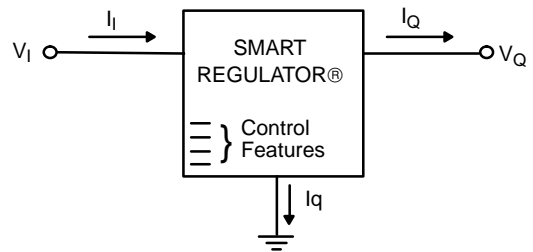

**Figure 4. Single Output Regulator with Key
Performance Parameters Labeled**

Heat Sinks

A heat sink effectively increases the surface area of the package to improve the flow of heat away from the IC and into the surrounding air.

Each material in the heat flow path between the IC and the outside environment will have a thermal resistance. Like series electrical resistances, these resistances are summed to determine the value of $R_{\theta JA}$:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CS} + R_{\theta SA} \qquad (3)$$

where

$R_{\theta JC}$	is the junction–to–case thermal resistance,
$R_{\theta CS}$	is the case–to–heatsink thermal resistance,
$R_{\theta SA}$	is the heatsink–to–ambient thermal resistance.

$R_{\theta JC}$ appears in the package section of the data sheet. Like $R_{\theta JA}$, it too is a function of package type. $R_{\theta CS}$ and $R_{\theta SA}$ are functions of the package type, heatsink and the interface between them. These values appear in data sheets of heat sink manufacturers.

Thermal, mounting, and heatsinking considerations are discussed in the ON Semiconductor application note AN1040/D.

Table 1. DPAK 5−Lead Thermal RC Network Models

Drain Copper Area (1 oz thick)			168 mm²	736 mm²		168 mm²	736 mm²	
(SPICE Deck Format)			Cauer Network			Foster Network		
			168 mm²	736 mm²	Units	Tau	Tau	Units
C_C1	**Junction**	**Gnd**	1.00E−06	1.00E−06	W−s/C	1.36E−08	1.361E−08	sec
C_C2	**node1**	**Gnd**	1.00E−05	1.00E−05	W−s/C	7.41E−07	7.411E−07	sec
C_C3	**node2**	**Gnd**	6.00E−05	6.00E−05	W−s/C	1.04E−05	1.029E−05	sec
C_C4	**node3**	**Gnd**	1.00E−04	1.00E−04	W−s/C	3.91E−05	3.737E−05	sec
C_C5	**node4**	**Gnd**	4.36E−04	3.64E−04	W−s/C	1.80E−03	1.376E−03	sec
C_C6	node5	Gnd	6.77E−02	1.92E−02	W−s/C	3.77E−01	2.851E−02	sec
C_C7	node6	Gnd	1.51E−01	1.27E−01	W−s/C	3.79E+00	9.475E−01	sec
C_C8	node7	Gnd	4.80E−01	1.018	W−s/C	2.65E+01	1.173E+01	sec
C_C9	node8	Gnd	3.740	2.955	W−s/C	8.71E+01	8.59E+01	sec
C_C10	node9	Gnd	10.322	0.438	W−s/C			sec
			168 mm²	736 mm²		R's	R's	
R_R1	**Junction**	**node1**	0.015	0.015	C/W	0.0123	0.0123	C/W
R_R2	**node1**	**node2**	0.08	0.08	C/W	0.0585	0.0585	C/W
R_R3	**node2**	**node3**	0.4	0.4	C/W	0.0304	0.0287	C/W
R_R4	**node3**	**node4**	0.2	0.2	C/W	0.3997	0.3772	C/W
R_R5	**node4**	**node5**	2.97519	2.6171	C/W	3.115	2.68	C/W
R_R6	node5	node6	8.2971	1.6778	C/W	3.571	1.38	C/W
R_R7	node6	node7	25.9805	7.4246	C/W	12.851	5.92	C/W
R_R8	node7	node8	46.5192	14.9320	C/W	35.471	7.39	C/W
R_R9	node8	node9	17.7808	19.2560	C/W	46.741	28.94	C/W
R_R10	node9	Gnd	0.1	0.1758	C/W			C/W

NOTE: Bold face items represent the package without the external thermal system.

Table 2. D^{2}PAK 5−Lead Thermal RC Network Models

Drain Copper Area (1 oz thick)			241 mm^2	788 mm^2		241 mm^2	788 mm^2	
(SPICE Deck Format)			Cauer Network			Foster Network		
			241 mm^2	653 mm^2	Units	Tau	Tau	Units
C_C1	**Junction**	**Gnd**	1.00E−06	1.00E−06	W−s/C	1.361E−08	1.361E−08	sec
C_C2	**node1**	**Gnd**	1.00E−05	1.00E−05	W−s/C	7.411E−07	7.411E−07	sec
C_C3	**node2**	**Gnd**	6.00E−05	6.00E−05	W−s/C	1.005E−05	1.007E−05	sec
C_C4	**node3**	**Gnd**	1.00E−04	1.00E−04	W−s/C	3.460E−05	3.480E−05	sec
C_C5	**node4**	**Gnd**	2.82E−04	2.87E−04	W−s/C	7.868E−04	8.107E−04	sec
C_C6	node5	Gnd	5.58E−03	5.95E−03	W−s/C	7.431E−03	7.830E−03	sec
C_C7	node6	Gnd	4.25E−01	4.61E−01	W−s/C	2.786E+00	2.012E+00	sec
C_C8	node7	Gnd	9.22E−01	2.05	W−s/C	2.014E+01	2.601E+01	sec
C_C9	node8	Gnd	1.73	4.88	W−s/C	1.134E+02	1.218E+02	sec
C_C10	node9	Gnd	7.12	1.31	W−s/C			sec
			241 mm^2	653 mm^2		R's	R's	
R_R1	**Junction**	**node1**	0.015	0.0150	C/W	0.0123	0.0123	C/W
R_R2	**node1**	**node2**	0.08	0.0800	C/W	0.0585	0.0585	C/W
R_R3	**node2**	**node3**	0.4	0.4000	C/W	0.0257	0.0260	C/W
R_R4	**node3**	**node4**	0.2	0.2000	C/W	0.3413	0.3438	C/W
R_R5	**node4**	**node5**	1.85638	1.8839	C/W	1.77	1.81	C/W
R_R6	node5	node6	1.23672	1.2272	C/W	1.54	1.52	C/W
R_R7	node6	node7	9.81541	5.3383	C/W	4.13	3.46	C/W
R_R8	node7	node8	33.1868	18.9591	C/W	6.27	5.03	C/W
R_R9	node8	node9	27.0263	13.3369	C/W	60.80	29.30	C/W
R_R10	node9	gnd	1.13944	0.1191	C/W			C/W

NOTE: Bold face items represent the package without the external thermal system.

The Cauer networks generally have physical significance and may be divided between nodes to separate thermal behavior due to one portion of the network from another. The Foster networks, though when sorted by time constant (as above) bear a rough correlation with the Cauer networks, are really only convenient mathematical models. Cauer networks can be easily implemented using circuit simulating tools, whereas Foster networks may be more easily implemented using mathematical tools (for instance, in a spreadsheet program), according to the following formula:

$$R(t) = \sum_{i=1}^{n} R_i \left(1 - e^{-t/tau_i}\right)$$
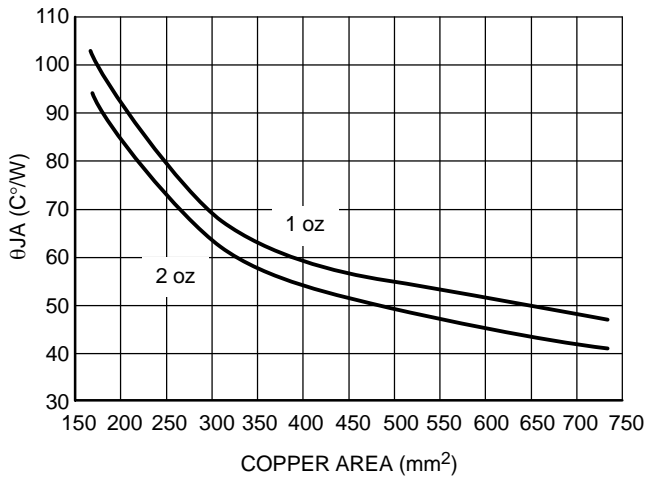
Figure 5. θJA vs. Copper Spreader Area, DPAK 5−Lead

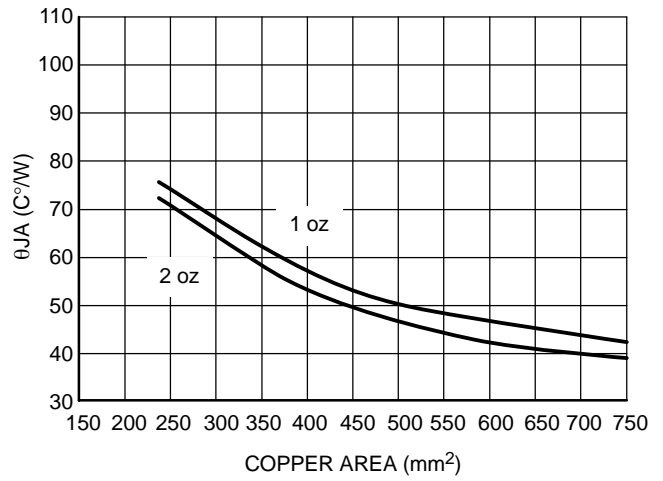**Figure 5. θJA vs. Copper Spreader Area, DPAK 5−Lead**

Figure 6. θJA vs. Copper Spreader Area, D^{2}PAK 5−Lead
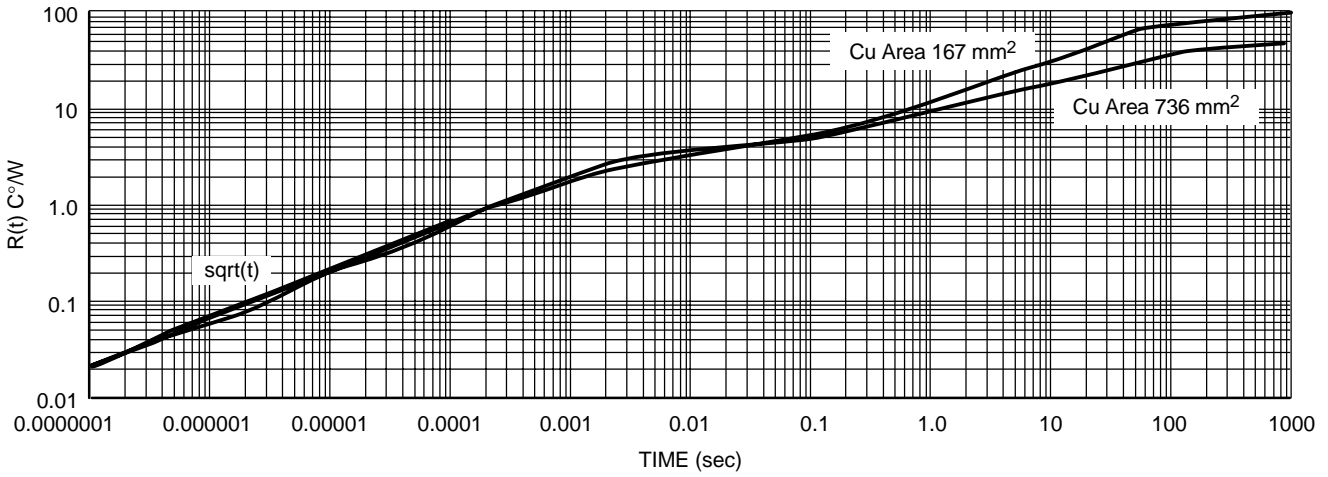
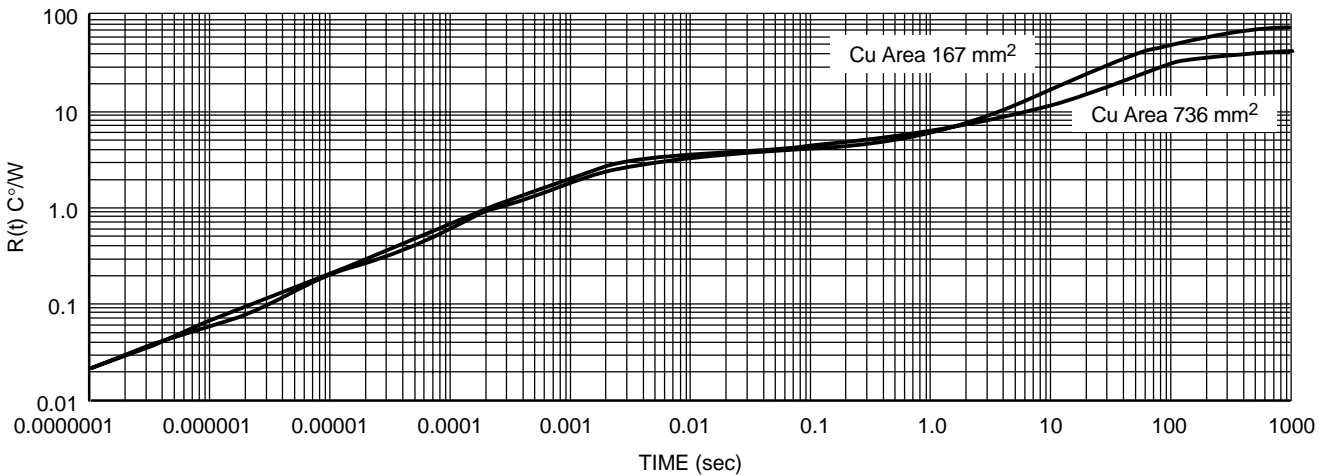**Figure 7. Single−Pulse Heating Curves, DPAK 5−Lead**

Figure 8. Single−Pulse Heating Curves, D^{2}PAK 5−Lead
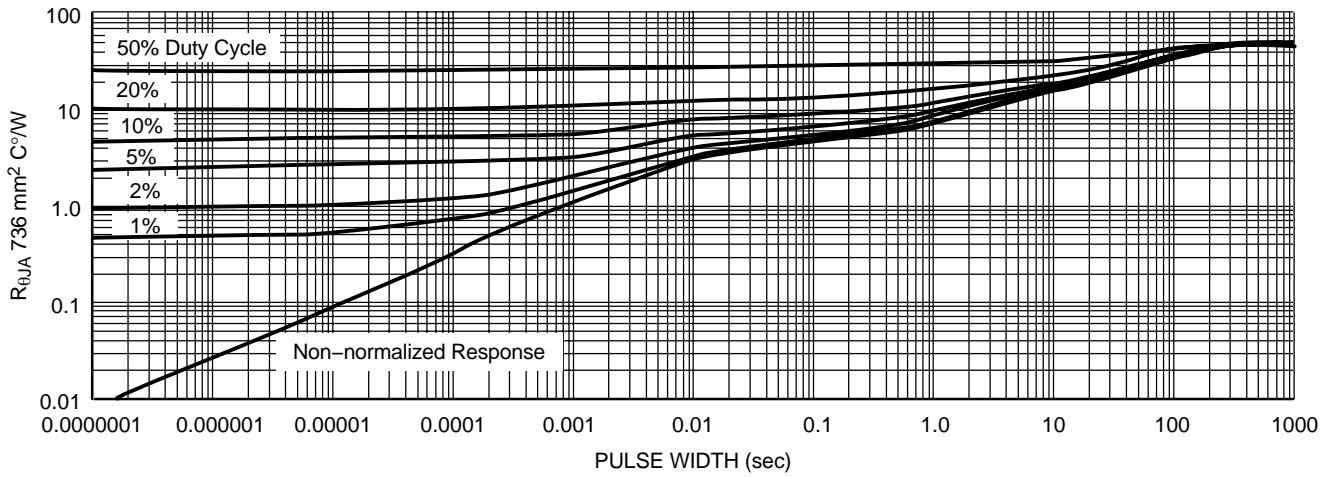
Figure 9. Duty Cycle for 1" Spreader Boards, DPAK 5−Lead
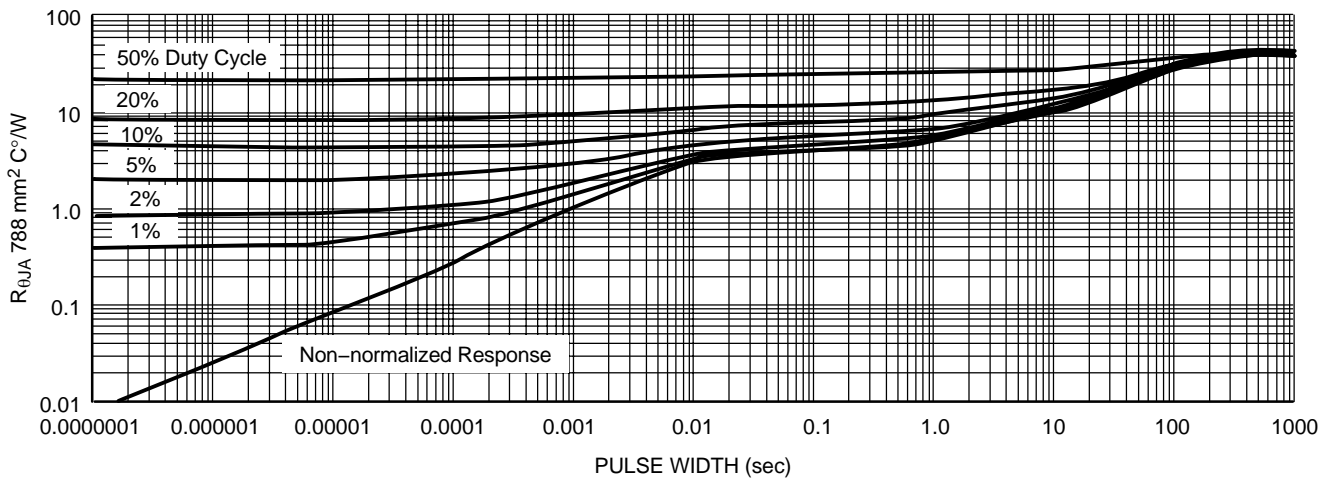
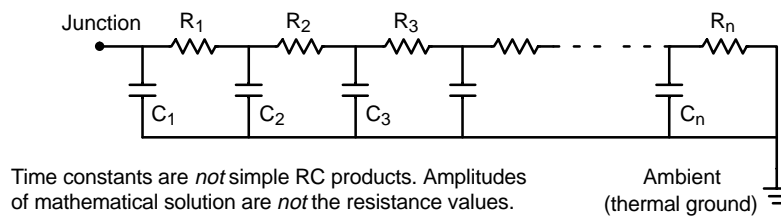**Figure 10. Duty Cycle for 1" Spreader Boards, D^{2}PAK 5−Lead**

Time constants are *not* simple RC products. Amplitudes of mathematical solution are *not* the resistance values.

Figure 11. Grounded Capacitor Thermal Network ("Cauer" Ladder)

Each rung is exactly characterized by its RC−product time constant; amplitudes are the resistances.
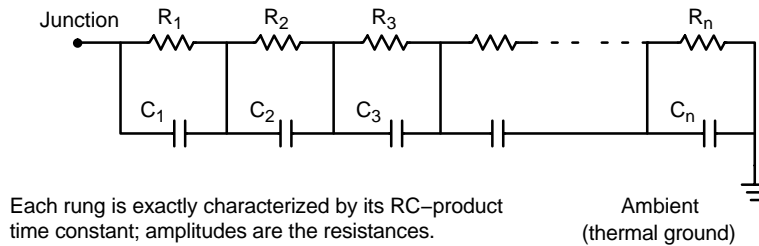
Figure 12. Non−Grounded Capacitor Thermal Ladder ("Foster" Ladder)

ORDERING INFORMATION

Device	Output Voltage	Package	Shipping
NCV4276DT50RK		DPAK, 5–Pin	2500 Tape & Reel
NCV4276DS50	5.0 V	D^2PAK, 5–Pin	50 Units / Rail
NCV4276DS50R4			800 Tape & Reel
NCV4276DT33RK		DPAK, 5–Pin	2500 Tape & Reel
NCV4276DS33	3.3 V	D^2PAK, 5–Pin	50 Units / Rail
NCV4276DS33R4			800 Tape & Reel
NCV4276DT25RK		DPAK, 5–Pin	2500 Tape & Reel
NCV4276DS25	2.5 V	D^2PAK, 5–Pin	50 Units / Rail
NCV4276DS25R4			800 Tape & Reel
NCV4276DT18RK		DPAK, 5–Pin	2500 Tape & Reel
NCV4276DS18	1.8 V	D^2PAK, 5–Pin	50 Units / Rail
NCV4276DS18R4			800 Tape & Reel

NCV4276

PACKAGE DIMENSIONS

DPAK 5 CENTER LEAD CROP
DT SUFFIX
CASE 175AA–01
ISSUE O
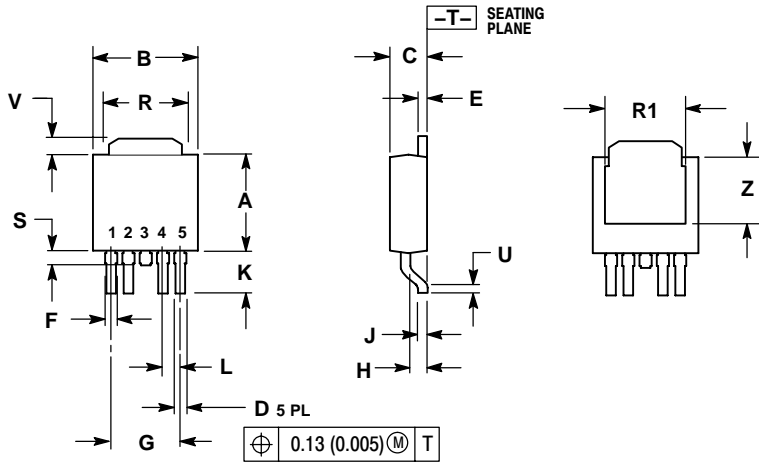
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	**MAX**	**MIN**	**MAX**
A	0.235	0.245	5.97	6.22
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.020	0.028	0.51	0.71
E	0.018	0.023	0.46	0.58
F	0.024	0.032	0.61	0.81
G	0.180 BSC		4.56 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.045 BSC		1.14 BSC	
R	0.170	0.190	4.32	4.83
R1	0.185	0.210	4.70	5.33
S	0.025	0.040	0.63	1.01
U	0.020	–––	0.51	–––
V	0.035	0.050	0.89	1.27
Z	0.155	0.170	3.93	4.32

NCV4276

PACKAGE DIMENSIONS

D²PAK
5 LEAD
DS SUFFIX
CASE 936A−02
ISSUE B
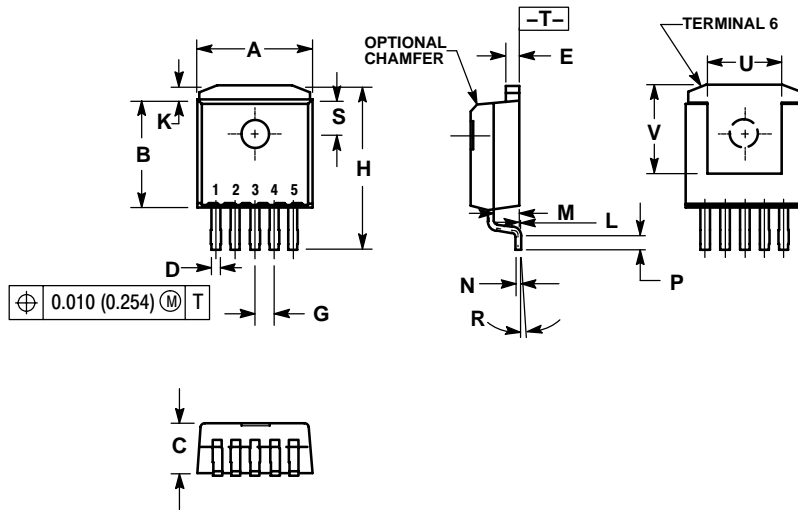
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. TAB CONTOUR OPTIONAL WITHIN DIMENSIONS A AND K.
4. DIMENSIONS U AND V ESTABLISH A MINIMUM MOUNTING SURFACE FOR TERMINAL 6.
5. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.025 (0.635) MAXIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.386	0.403	9.804	10.236
B	0.356	0.368	9.042	9.347
C	0.170	0.180	4.318	4.572
D	0.026	0.036	0.660	0.914
E	0.045	0.055	1.143	1.397
G	0.067 BSC		1.702 BSC	
H	0.539	0.579	13.691	14.707
K	0.050 REF		1.270 REF	
L	0.000	0.010	0.000	0.254
M	0.088	0.102	2.235	2.591
N	0.018	0.026	0.457	0.660
P	0.058	0.078	1.473	1.981
R	5° REF		5° REF	
S	0.116 REF		2.946 REF	
U	0.200 MIN		5.080 MIN	
V	0.250 MIN		6.350 MIN	